

MCC

Micro Commercial Components
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FR3A THRU FR3M

Features

- For Surface Mount Applications
- Extremely Low Thermal Resistance
- Easy Pick And Place
- High Temp Soldering: 250°C for 10 Seconds At Terminals
- Fast Recovery Times For High Efficiency

Maximum Ratings

- Operating Temperature: -55°C to +150°C
- Storage Temperature: -55°C to +150°C
- Maximum Thermal Resistance; 10°C/W Junction To Lead

MCC Catalog Number	Device Marking	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
FR3A	FR3A	50V	35V	50V
FR3B	FR3B	100V	70V	100V
FR3D	FR3D	200V	140V	200V
FR3G	FR3G	400V	280V	400V
FR3J	FR3J	600V	420V	600V
FR3K	FR3K	800V	560V	800V
FR3M	FR3M	1000V	700V	1000V

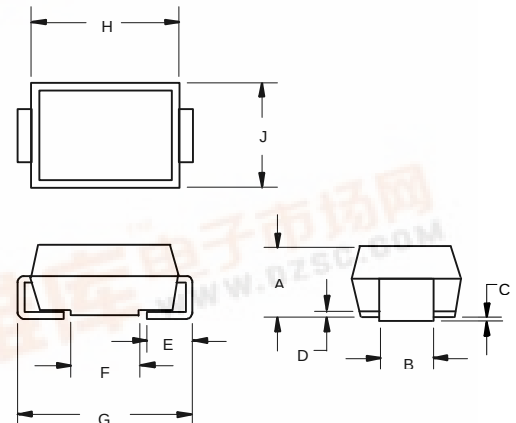
Electrical Characteristics @ 25°C Unless Otherwise Specified

Average Forward Current	$I_{F(AV)}$	3.0A	$T_J = 120^\circ\text{C}$
Peak Forward Surge Current	I_{FSM}	100A	8.3ms, half sine
Maximum Instantaneous Forward Voltage	V_F	1.30V	$I_{FM} = 3.0A$; $T_J = 25^\circ\text{C}^*$
Maximum DC Reverse Current At Rated DC Blocking Voltage	I_R	10 μA 250 μA	$T_J = 25^\circ\text{C}$ $T_J = 100^\circ\text{C}$
Maximum Reverse Recovery Time	T_{rr}	150ns 250ns 500ns	$I_F = 0.5A$, $I_R = 1.0A$, $I_{rr} = 0.25A$
Typical Junction Capacitance	C_J	80pF	Measured at 1.0MHz, $V_R = 4.0V$

*Pulse test. Pulse width 200 μsec , Duty cycle 2%

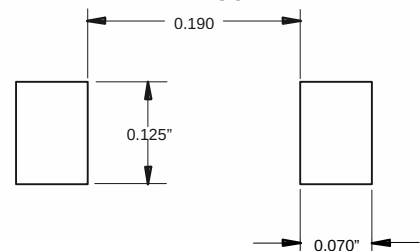
3 Amp Fast Recovery Silicon Rectifier 50 to 1000 Volts

DO-214AB (SMCJ)



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.079	.103	2.00	2.62	
B	.108	.128	2.75	3.25	
C	.002	.008	.051	.203	
D					
E	.030	.050	.76	1.27	
F					
G	.305	.320	7.75	8.13	
H	.260	.280	6.60	7.11	
J	.220	.245	5.59	6.22	

SUGGESTED SOLDER PAD LAYOUT



FR3A thru FR3M



Figure 1
Typical Forward Characteristics

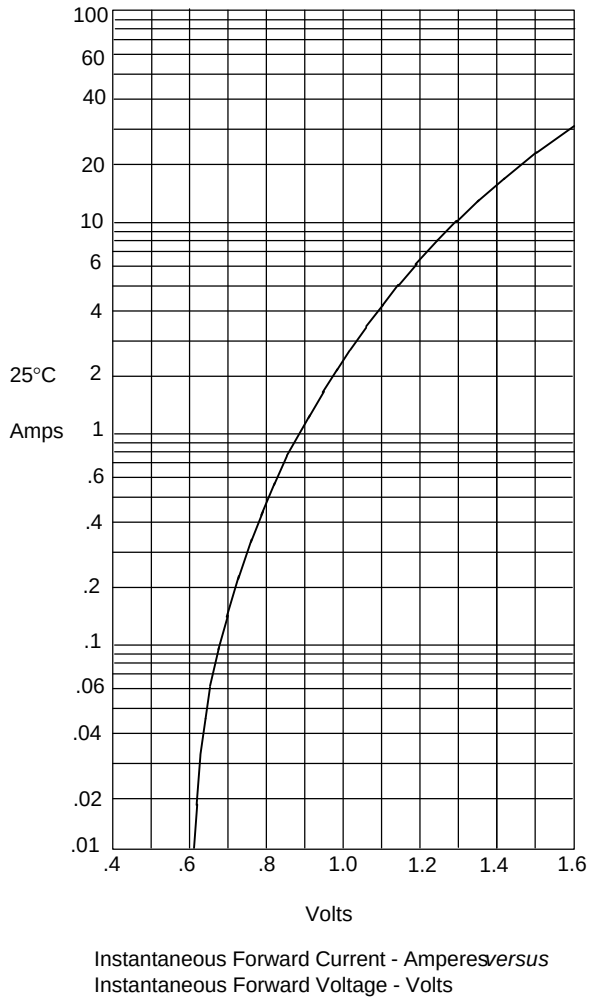


Figure 2
Forward Derating Curve

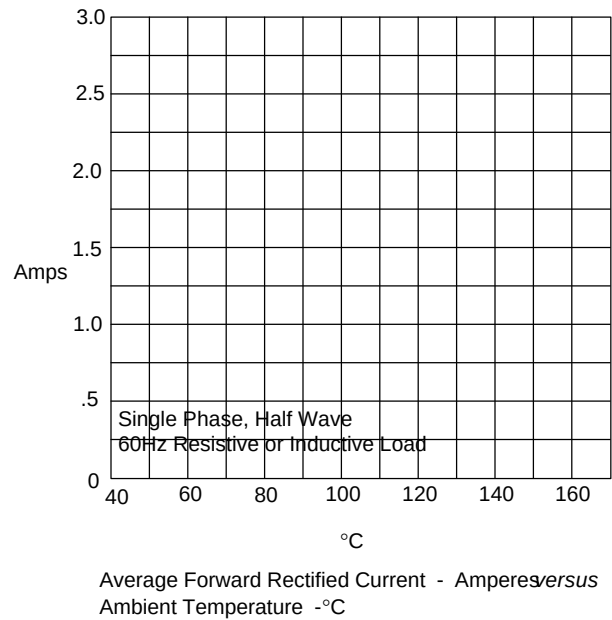
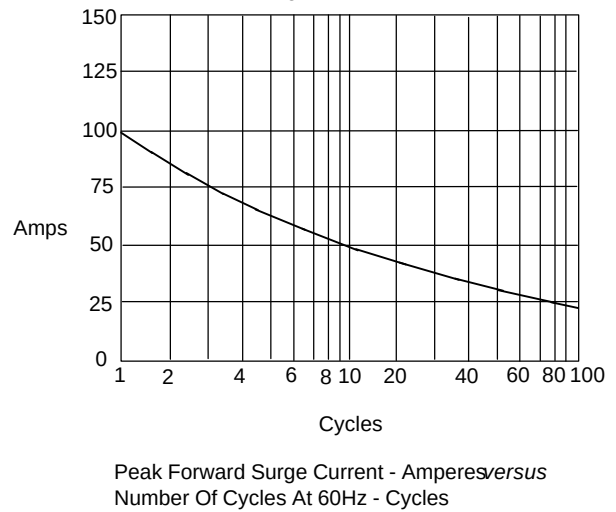


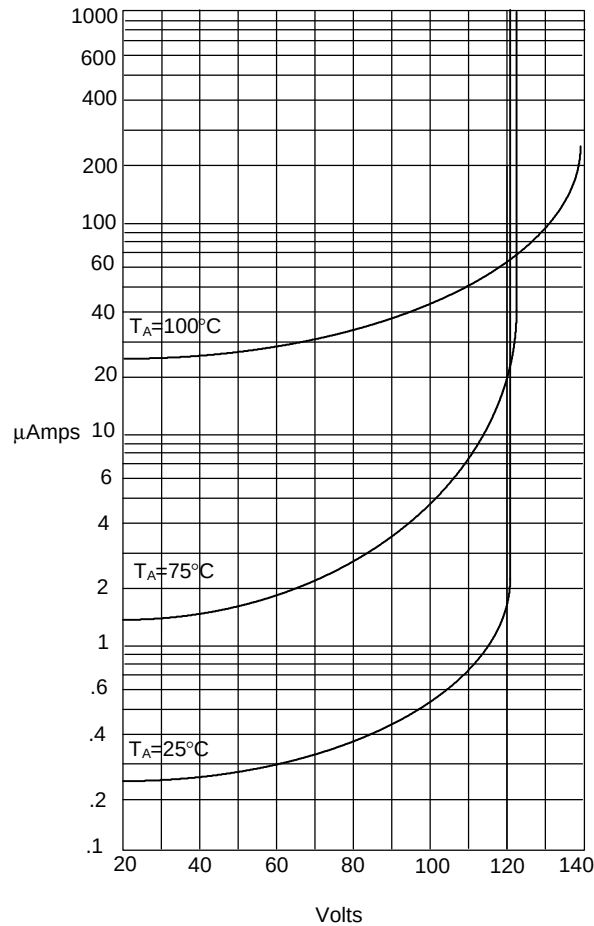
Figure 3
Peak Forward Surge Current



FR3A thru FR3M

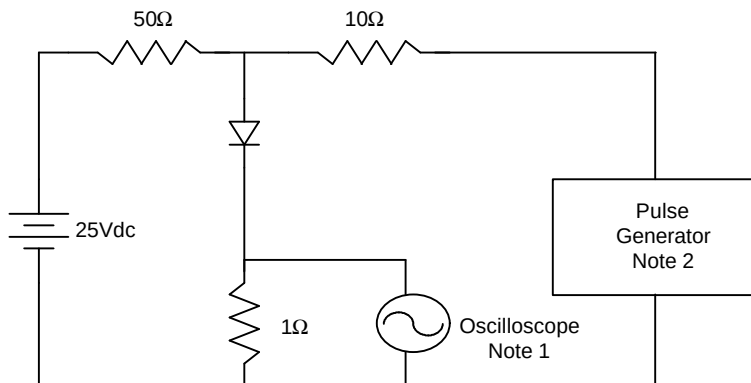


Figure 4
Typical Reverse Characteristics



Instantaneous Reverse Leakage Current - MicroAmperes versus
Percent Of Rated Peak Reverse Voltage - Volts

Figure 5
Reverse Recovery Time Characteristic And Test Circuit Diagram



Notes:

1. Rise Time = 7ns max.
Input impedance = 1 megohm, 22pF
2. Rise Time = 10ns max.
Source impedance = 50 ohms
3. Resistors are non-inductive

